

PSMN3R4-30BLE

N-channel 30 V 3.4 m Ω logic level MOSFET in D2PAK **Product data sheet**

1. **Product profile**

1.1 General description

Logic level N-channel MOSFET in D2PAK package qualified to 175 °C. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- Enhanced forward biased safe operating area for superior linear mode operation
- Very low Rdson for low conduction losses

1.3 Applications

- Electronic fuse
- Hot swap
- Load switch
- Soft start

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|---------------------|----------------------------------|---|-----|-----|------|-----|------|
| V _{DS} | drain-source voltage | T _j ≥ 25 °C; T _j ≤ 175 °C | | - | - | 30 | V |
| I _D | drain current | T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u> | [1] | - | - | 120 | Α |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; <u>Fig. 2</u> | | - | - | 178 | W |
| Static charact | eristics | | | | | | |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 12 | | - | 2.95 | 3.4 | mΩ |
| | | V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C; Fig. 12 | | - | 4.25 | 5 | mΩ |
| Dynamic char | acteristics | | | | | | |
| Q_{GD} | gate-drain charge | V _{GS} = 4.5 V; I _D = 25 A; V _{DS} = 15 V; Fig. 14; Fig. 15 | | - | 12.2 | - | nC |
| Q _{G(tot)} | total gate charge | V _{GS} = 10 V; I _D = 25 A; V _{DS} = 15 V; Fig. 14; Fig. 15 | | - | 81 | - | nC |



| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------|---|---|--|-----|-----|-----|------|
| Avalanche ruggedness | | | | | | | |
| E _{DS(AL)S} | non-repetitive drain- source avalanche energy | V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 120 A; $V_{sup} \le$ 30 V; unclamped; R_{GS} = 50 Ω; Fig. 3 | | - | - | 246 | mJ |

[1] Capped at 120A due to package

Pinning information

Table 2. **Pinning information**

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|--------------------|----------------|
| 1 | G | gate | mb | D I |
| 2 | D | drain[1] | | |
| 3 | S | source | | G—U: 4 |
| mb | D | mounting base; connected to drain | D2PAK (SOT404) | mbb076 S |

[1] It is not possible to make connection to pin 2.

Ordering information

Table 3. **Ordering information**

| Type number | Package | kage | | | | |
|---------------|---------|--|---------|--|--|--|
| | Name | Description | Version | | | |
| PSMN3R4-30BLE | D2PAK | plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) | SOT404 | | | |

Marking

Table 4. **Marking codes**

| Type number | Marking code |
|---------------|---------------|
| PSMN3R4-30BLE | PSMN3R4-30BLE |

Limiting values 5.

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------|----------------------|---|------------|----------------|-----------------|
| V_{DS} | drain-source voltage | $T_j \ge 25 \text{ °C}; T_j \le 175 \text{ °C}$ | - | 30 | ٧ |
| V_{DGR} | drain-gate voltage | $T_j \le 175 ^{\circ}\text{C}; T_j \ge 25 ^{\circ}\text{C}; R_{GS} = 20 \text{k}\Omega$ | - | 30 | V |
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| Symbol | Parameter | Conditions | | Min | Max | Unit |
|----------------------|--|---|-----|-----|-----|------|
| V _{GS} | gate-source voltage | | | -20 | 20 | V |
| I _D | drain current | V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 1</u> | | - | 119 | Α |
| | | V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u> | [1] | - | 120 | Α |
| I _{DM} | peak drain current | pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 4 | | - | 672 | Α |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; <u>Fig. 2</u> | | - | 178 | W |
| T _{stg} | storage temperature | | | -55 | 175 | °C |
| Tj | junction temperature | | | -55 | 175 | °C |
| T _{sld(M)} | peak soldering temperature | | | - | 260 | °C |
| Source-drai | in diode | | | | | |
| Is | source current | T _{mb} = 25 °C | [1] | - | 120 | Α |
| I _{SM} | peak source current | pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$ | | - | 672 | Α |
| Avalanche r | ruggedness | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 120 A; $V_{sup} \le$ 30 V; unclamped; R_{GS} = 50 Ω ; Fig. 3 | | - | 246 | mJ |

[1] Capped at 120A due to package

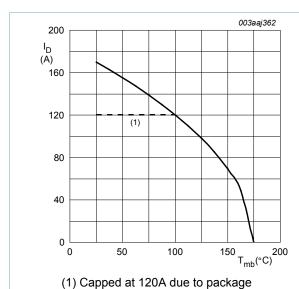


Fig. 1. Continuous drain current as a function of mounting base temperature

$$V_{GS} \ge 10V$$

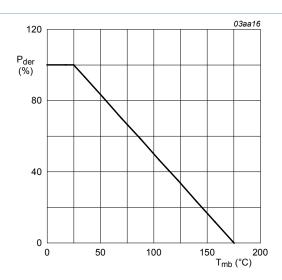


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

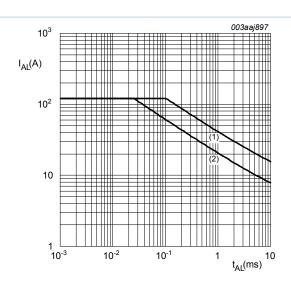


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time

(1)
$$T_{j \ (init)} = 25^{\circ}C$$
; (2) $T_{j \ (init)} = 100^{\circ}C$

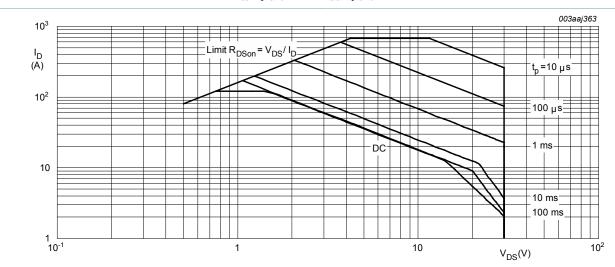


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$$T_{mb} = 25^{\circ}C$$
; I_{DM} is a single pulse

6. Thermal characteristics

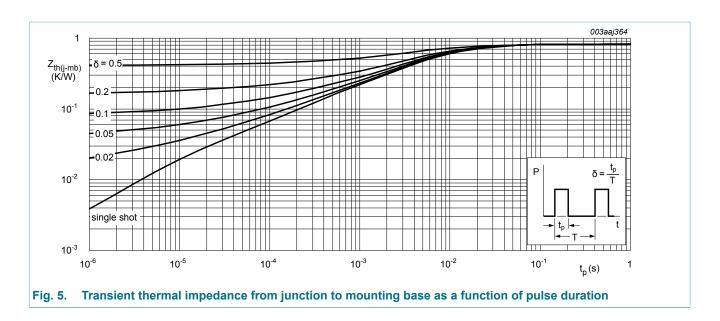
Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---|------------------------------|-----|------|------|------|
| R _{th(j-mb)} | thermal resistance from junction to mounting base | Fig. 5 | - | 0.73 | 0.84 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | minimum footprint; FR4 board | - | 50 | - | K/W |

PSMN3R4-30BLE

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7. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--|---|--|-----|------|------|------|
| Static chara | acteristics | | | | | |
| V _{(BR)DSS} | | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$ | 27 | - | - | V |
| | breakdown voltage | $I_D = 250 \ \mu A; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^{\circ}C$ | 30 | - | - | V |
| V _{GS(th)} | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ Fig. 10 | 0.5 | - | - | V |
| | | I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 25 °C; Fig. 11; Fig. 10 | 1.3 | 1.7 | 2.15 | V |
| | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 10 | - | - | 2.45 | V | |
| I _{DSS} drain leakage current | drain leakage current | $V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$ | - | 0.2 | 5 | μA |
| | | $V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 100 ^{\circ}\text{C}$ | - | - | 100 | μA |
| I _{GSS} | gate leakage current | V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C | - | 10 | 100 | nA |
| | | V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C | - | 10 | 100 | nA |
| R _{DSon} | drain-source on-state resistance | V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 12 | - | 2.95 | 3.4 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _j = 100 °C; Fig. 13; Fig. 12 | - | - | 5.1 | mΩ |
| | | V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C; Fig. 12 | - | 4.25 | 5 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 13; Fig. 12 | - | - | 6.5 | mΩ |

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------------|---------------------------------------|---|----------|------|-----|------|
| R_G | internal gate resistance (AC) | f = 1 MHz | 0.5 | 1 | 2 | Ω |
| Dynamic ch | aracteristics | | , | | | |
| Q _{G(tot)} | total gate charge | I _D = 25 A; V _{DS} = 15 V; V _{GS} = 10 V; Fig. 14; Fig. 15 | - | 81 | - | nC |
| | | I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V; Fig. 14; Fig. 15 | - | 37 | - | nC |
| | | I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V | - | 79 | - | nC |
| Q _{GS} | gate-source charge | I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V; | - | 13.9 | - | nC |
| Q _{GS(th)} | pre-threshold gate- source charge | Fig. 14; Fig. 15 | - | 7.5 | - | nC |
| Q _{GS(th-pl)} | post-threshold gate- source charge | | - | 6.4 | - | nC |
| Q_{GD} | gate-drain charge | | - | 12.2 | - | nC |
| $V_{GS(pl)}$ | gate-source plateau voltage | I _D = 25 A; V _{DS} = 15 V; <u>Fig. 14</u> ; <u>Fig. 15</u> | - | 3.2 | - | V |
| C _{iss} | input capacitance | V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz; | - | 4682 | - | pF |
| C _{oss} | output capacitance | T _j = 25 °C; <u>Fig. 16</u> | - | 909 | - | pF |
| C _{rss} | reverse transfer capacitance | | - | 438 | - | pF |
| t _{d(on)} | turn-on delay time | V_{DS} = 15 V; R_L = 0.6 Ω ; V_{GS} = 4.5 V; | - | 35.7 | - | ns |
| t _r | rise time | $R_{G(ext)} = 4.7 \Omega; T_j = 25 °C$ | - | 101 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 49 | - | ns |
| t _f | fall time | | - | 51.2 | - | ns |
| Source-drai | in diode | 1 | <u> </u> | | 1 | |
| V _{SD} | source-drain voltage | I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 17</u> | - | 0.85 | 1.2 | V |
| t _{rr} | reverse recovery time | $I_S = 25 \text{ A}; dI_S/dt = 100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$ | - | 37 | - | ns |
| Q _r | recovered charge | V _{DS} = 15 V | - | 38 | - | nC |

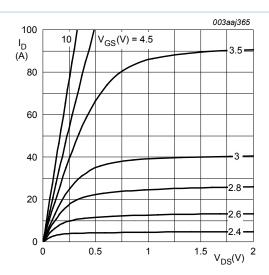


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values



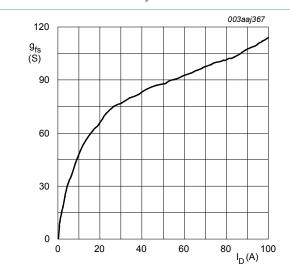


Fig. 8. Forward transconductance as a function of drain current; typical values

$$T_j = 25$$
°C; $V_{DS} = 10V$

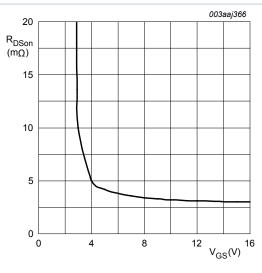


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25^{\circ}C; I_D = 25A$$

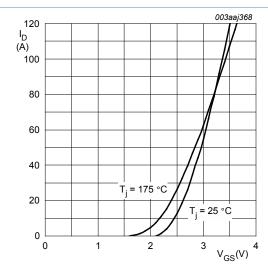


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

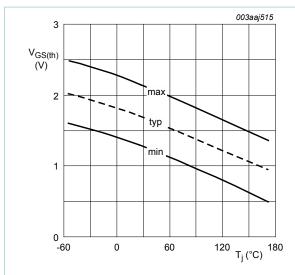


Fig. 10. Gate-source threshold voltage as a function of junction temperature

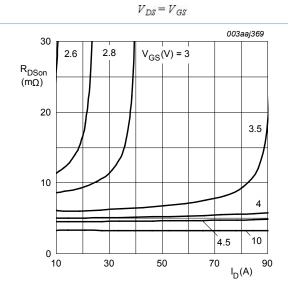


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$$T_j=25^{\circ}C$$

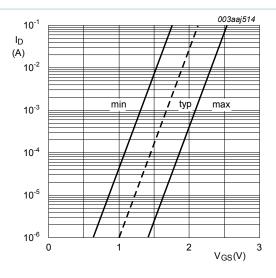


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25^{\circ}C; \ V_{DS} = 5V$$

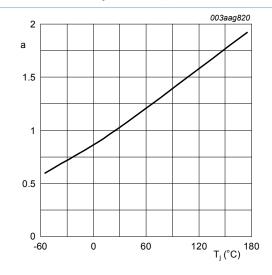


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$\mathbf{a} = \frac{R_{DSon}}{R_{DSon(25 \, ^{\circ}\text{C})}}$$

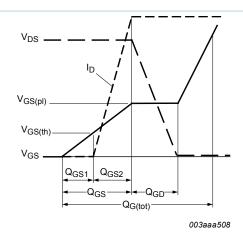


Fig. 14. Gate charge waveform definitions

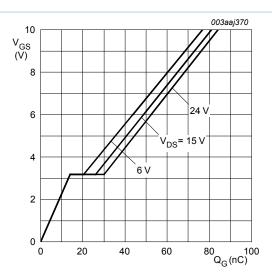


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^{\circ}C; I_D = 25A$$

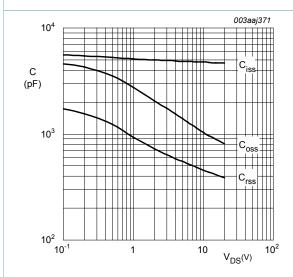
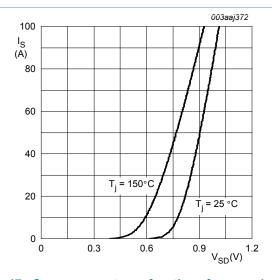


Fig. 16. Input, output and reverse transfer capacitances | Fig. 17. Source current as a function of source-drain as a function of drain-source voltage; typical values

$$V_{GS} = \mathbf{0}V; \ f = \mathbf{1}MHz$$



voltage; typical values

$$V_{GS} = 0V$$

8. Package outline

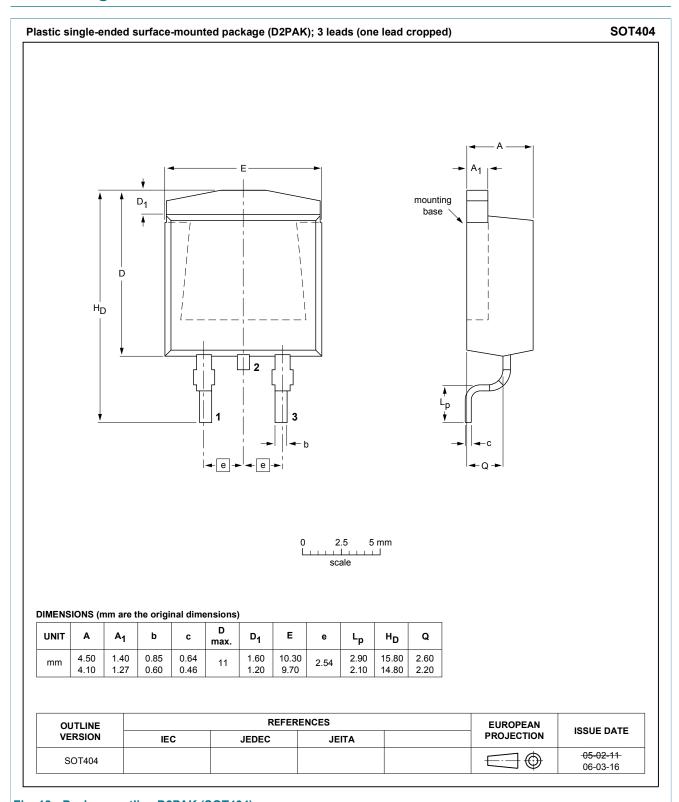


Fig. 18. Package outline D2PAK (SOT404)

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|--------------------------------------|--------------------|---|
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